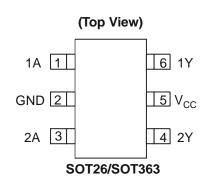


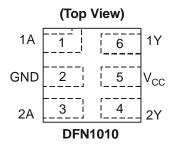
DUAL INVERTER WITH OPEN DRAIN OUTPUTS

Description

The 74LVC2G06 is a dual inverter gate with open drain outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The input is tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down. The open-drain output can be connected to other open drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32 mA.

Pin Assignments





Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- -24mA Output Drive at 3.0V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- SOT26, SOT363, and DFN1010 Available in "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

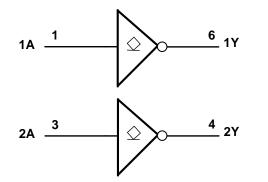


DUAL INVERTER WITH OPEN DRAIN OUTPUTS

Pin Descriptions

Pin Name	Pin NO.	Description			
1A	1	Data Input			
GND	2	Ground			
2A	3	Data Input			
2Y	4	Data Output Open Drain			
V _{CC}	5	Supply Voltage			
1Y	6	Data Output Open Drain			

Logic Diagram



Function Table

Inputs	Output
Α	Y
н	L
L	Z



Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI<0	-50	mA
I _{OK}	Output Clamp Current V _O <0	-50	mA
Ι _Ο	Continuous output current	-50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

Symbol		Parameter	Min	Max	Unit	
Mara	Operating Voltage	Operating	1.65	5.5	V	
V _{CC}	Operating Voltage	Data retention only	1.5		V	
		V _{CC} = 1.65V to 1.95V	$0.65 \times V_{CC}$			
V _{IH}	High lovel logut Veltage	$V_{CC} = 2.3 V$ to 2.7V	1.7		V	
	High-level Input Voltage	$V_{CC} = 3V$ to 3.6V	2		V	
		$V_{CC} = 4.5V$ to 5.5V	0.7 X V _{CC}			
		V _{CC} = 1.65V to 1.95V		$0.35 \times V_{CC}$		
N/	Low-level input voltage	V _{CC} = 2.3V to 2.7V		0.7	V	
VIL		$V_{CC} = 3V$ to 3.6V		0.8		
		$V_{CC} = 4.5V$ to 5.5V		$0.3 \times V_{CC}$		
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V _{CC}	V	
		$V_{CC} = 1.65 V$		4		
		$V_{CC} = 2.3V$		8		
I _{OL}	Low-level output current	N/ 2N/		16	mA	
		$V_{CC} = 3V$		24		
		$V_{CC} = 4.5V$		32		
		$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$		20		
Δt/ΔV	Input transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$		10	ns/V	
		$V_{CC} = 5V \pm 0.5V$		10		
T _A	Operating free-air temperature		-40	125	°C	

Notes: 3. Unused inputs should be held at V_{CC} or Ground.



DUAL INVERTER WITH OPEN DRAIN OUTPUTS

Electrical Characteristics

0h.el	Demonster	Tast Osmilitiana		40ºC t	o 85⁰C	-40°C te	o 125⁰C	
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit
		I _{OL} = 100μA	1.65V to 5.5V		0.1		0.1	
N/		$I_{OL} = 4mA$	1.65V		0.45		0.70	
	Low Level Output	I _{OL} = 8mA	2.3V		0.3		0.45	v
V _{OL}	Voltage	I _{OL} = 16mA	2)/		0.4		0.60	V
		I _{OL} = 24mA	3V		0.55		0.80	
		I _{OL} = 32mA	4.5V		0.55		0.80	
l _l	Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5V		± 5		± 20	μA
I _{OZ}	Z State Leakage Current	V _O =0 to 5.5V	3.6V		± 10		± 10	μA
I _{OFF}	Power Down Leakage Current	$V_{\rm I}$ or $V_{\rm O} = 5.5 V$	0		± 10		± 20	μA
I _{CC}	Supply Current	V _I = 5.5V of GND I _O =0	1.65V to 5.5V		10		40	μA
ΔI _{CC}	Additional Supply Current	Input at V _{CC} –0.6V	3V to 5.5V		500		5000	μA

Package Characteristics (All typical values are at $V_{CC} = 3.3V$, $T_A = 25^{\circ}C$)

Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Unit	
CI	Input Capacitance	$V_{I} = V_{CC} - or GND$	3.3		3.5		рF	
The med Decisters	Thermal Decistories	SOT26			204			
θ_{JA}	Thermal Resistance Junction-to-Case	SOT363	(Note 4)		371		°C/W	
	Junction-to-Case	DFN1010			430			
	Thermal Decistories	SOT26			52		°C/W	
θ _{JC}	Thermal Resistance	SOT363	(Note 4)		143			
	Junction-to-Case	DFN1010			190			

Notes: 4. Test condition for SOT26, SOT363 and DFN1010: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

T_A = -40°C to 85°C, CL = 30 or 50pF (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)		= 1.8V .15V		= 2.5V).2V	V _{CC} = ± 0	= 3.3V).3V		= 5V).5V	Unit
	(input)	(001701)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	А	Y	0.5	6.5	0.5	3.9	0.5	3.4	0.5	2.9	ns

T_A = -40°C to 125°C, CL = 30 or 50pF (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)		: 1.8V .15V		= 2.5V 0.2V	= V _{CC} + 0	: 3.3V .3V		= 5V .5V	Unit
	(input)	(001701)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	А	Y	0.5	8.2	0.5	4.9	0.5	4.3	0.5	3.7	ns

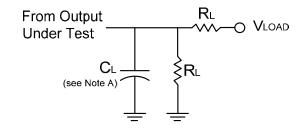


Operating Characteristics

$T_{A} = 25 \ ^{\circ}C$

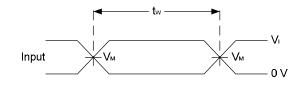
	Parameter	Test Conditions	V _{CC} = 1.8V Typ.	V _{CC} = 2.5V Typ.	V _{CC} = 3.3V Typ.	V _{CC} = 5V Typ.	Unit
C _{pd}	Power dissipation capacitance	f = 10 MHz	3	3	4	6	pF

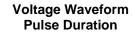
Parameter Measurement Information

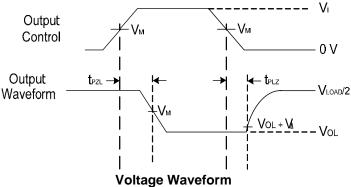


TEST	Condition
t _{PLZ} (see Notes D and E)	Vload
t _{PZL} (see Notes D and F)	Vload

V	Inputs		V	N	^	в	MA	
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	RL	VΔ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30 pF	1 KΩ	0.15 V	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30 pF	500 Ω	0.15 V	
3.3V±0.3V	3 V	≤2.5ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	2 X V _{CC}	50 pF	500 Ω	0.3 V	







Propagation Delay Times

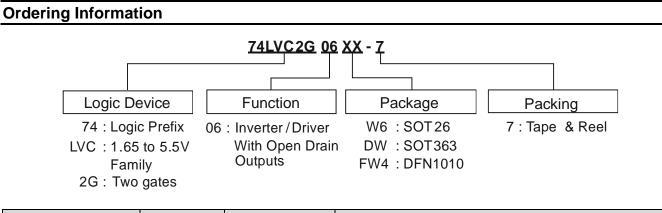
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD}
- E. t_{PZL} is measured at V_M.
- F. t_{PLZ} is measured at V_OL +V_ Δ



DUAL INVERTER WITH OPEN DRAIN OUTPUTS



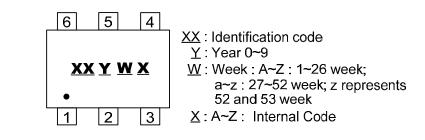
Γ	Daviaa	Device Package		7" Tape and Reel			
	Device	Code	(Note 5)	Quantity	Part Number Suffix		
Pb ,	74LVC2G06W6-7	W6	SOT26	3000/Tape & Reel	-7		
Pb ,	74LVC2G06DW-7	DW	SOT363	3000/Tape & Reel	-7		
P ,	74LVC2G06FW4-7	FW4	DFN1010	5000/Tape & Reel	-7		

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf

6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SOT26, SOT363

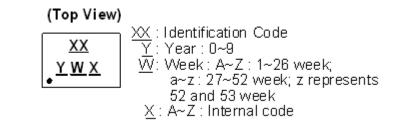


Part Number	Package	Identification Code
74LVC2G06W6	SOT26	Z3
74LVC2G06DW	SOT363	Z3



Marking Information (cont.)

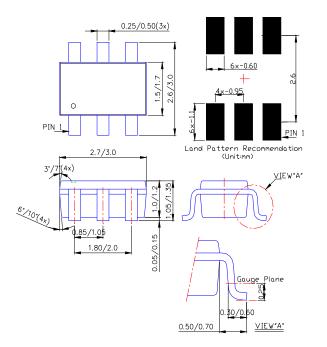
(2) DFN1010



Part Number	Package	Identification Code
74LVC2G06FW4	DFN1010	Z3

Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT26

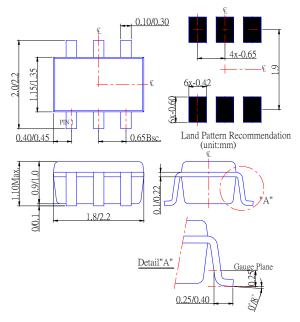




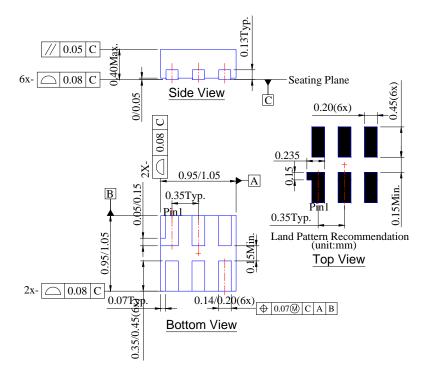
DUAL INVERTER WITH OPEN DRAIN OUTPUTS

Package Outline Dimensions (cont.) (All Dimensions in mm)

(2) Package Type: SOT363



(3) Package Type: DFN1010



74LVC2G06 Document number: DS35161 Rev. 3 - 2





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